

Features

- Low noise and high speed transimpedance amplifier built-in for optical data links in the wavelength of 850nm
- High reliability
- 5 pin package available for an independent PD connection or input power monitoring
- Pigtail type and LC-ROSA are available as an option

Applications

- High speed data communications
- 1x/2x/4x Fibre Channel receivers
- Gigabit ethernet



CAN package type

1) KPGX1GK**Absolute Maximum Ratings**

Parameter	Symbol	Value		Unit	Note
Supply voltage	V _{CC}	-0.5 to 6.5		V	
Operating temperature	T _{opr}	-40 to +85		°C	
Storage temperature	T _{stg}	-40 to +85		°C	

Electrical and Optical Characteristics (Ta=25°C unless otherwise noted)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Operating voltage	V _{op}	3.0	3.3	3.6	V	
Supply current	I _{CC}	30	42	55	mA	
Bit rate	BR	-	1.25	-	Gbps	
Band width @-3dB	BW	-	800	-	MHz	R _L =50Ω, P _i =-10dBm
Optical sensitivity	P _{min}	-	-24	-	dBm	differential, BER=10 ⁻¹²
Output impedance	Z _O	-	50	-	Ω	single ended
Differential output voltage	V _O	-	400	-	mVpp	differential, R _L =100Ω
Photo-electric conversion efficiency	η _{PE}	-	11	-	kV/W	single ended, R _L =50Ω

2) KPGX2GK

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit	Note
Supply voltage	V_{CC}	-0.5 to 6.0	V	
Operating temperature	T_{opr}	-40 to +85	°C	
Storage temperature	T_{stg}	-40 to +85	°C	

Electrical and Optical Characteristics (Ta=25°C unless otherwise noted)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Operating voltage	V_{op}	3.0	3.3	3.6	V	
Supply current	I_{CC}	-	48	-	mA	
Bit rate	BR	-	2.5	-	Gbps	
Band width @-3dB	BW	-	1.8	-	GHz	$R_L=50\Omega, P_i=-10\text{dBm}$
Optical sensitivity	P_{min}	-	-20	-	dBm	differential, BER=10 ⁻¹²
Output impedance	Z_O	40	50	60	Ω	single ended
Differential output voltage	V_O	160	200	240	mVpp	$R_L=50\Omega$
Photo-electric conversion efficiency	η_{PE}	-	6.25	-	kV/W	single ended, $R_L=50\Omega$

3) KPGX4G

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit	Note
Supply voltage	V_{CC}	-0.3 to 4	V	
Operating temperature	T_{opr}	-40 to +85	°C	
Storage temperature	T_{stg}	-40 to +85	°C	

Electrical and Optical Characteristics (Ta=25°C unless otherwise noted)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Operating voltage	V_{op}	3.0	3.3	3.6	V	
Supply current	I_{CC}	11	17	25	mA	
Bit rate	BR	-	4.25	-	Gbps	
Band width @-3dB	BW	2.2	2.8	-	GHz	$R_L=50\Omega, P_i=-10\text{dBm}$
Optical sensitivity	P_{min}	-	-17	-	dBm	differential, BER=10 ⁻¹⁰
Output impedance	Z_O	-	50	-	Ω	single ended
Differential output voltage	V_O	85	130	187	mVpp	single ended, $R_L=50\Omega$
Photo-electric conversion efficiency	η_{PE}	-	1.6	-	kV/W	single ended, $R_L=50\Omega$

- Specifications , characteristics, data, materials, structures specified in this datasheet are subject to change without notice. Please refer to the latest specification before use of the products.
- Products listed in this datasheet comply with the RoHS Directive (EU2002/95/EC).

Opto-technologies for the Future



KYOSEMI CORPORATION

<http://www.kyosemi.co.jp/>

Headquarters : 949-2 Ebisicho Fushimi-ku, Kyoto 612-8201 Japan

TEL: +81-75-605-7311

Tokyo Sales Office: 24th Sky Bldg.2F, 1-34-3 Shinjuku Shinjuku-ku, Tokyo 160-0022 Japan

TEL: +81-3-5312-5360

Kansai Sales Office: 949-2 Ebisicho Fushimi-ku, Kyoto 612-8201 Japan

TEL: +81-75-605-7311

Kyosemi Opto America Corp: 4655 Old Ironsides Suite 230 Santa Clara, California 95054 USA

TEL: +1-408-492-9361

Eniwa Operation: 385-31 Toiso Eniwa-shi, Hokkaido 061-1405 Japan

TEL: +81-123-34-3111

Kamisunagawa Operation: 70-1 Kamisunagawa Kamisunagawa-cho Sorachi-gun, Hokkaido 073-0200 Japan

TEL: +81-125-62-3611